# NSN 5961-01-119-8253

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Inclosure N	laterial:

Metal

**Overall Length:** 

0.196 inches

# Terminal Length:

0.500 inches

# **Overall Diameter:**

0.330 inches

#### Internal Configuration:

Junction contact

#### Internal Junction Configuration:

Npn

#### **Mounting Method:**

Terminal

#### Terminal Circle Diameter:

0.100 inches

#### Features Provided:

Hermetically sealed case

# **Criticality Code Justification:**

Feat

# Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

40.0 breakdown voltage, collector-to-base, emitter open and 20.0 breakdown voltage, collector-to-emitter, base open and 4.0 breakdown voltage, emitter-to-base, collector open

#### **Current Rating Per Characteristic:**

300.00 milliamperes source cutoff current

#### **Power Rating Per Characteristic:**

1.2 watts small-signal input power, common-collector preset

# Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

# **Special Features:**

Nuclear hardness critical item; junction pattern arrangement: npn

# **Nuclear Hardness Critical Feature:**

Hardened

# Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

#### Unit Of Measure:

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# Demilitarization:

No

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